

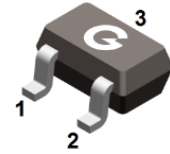
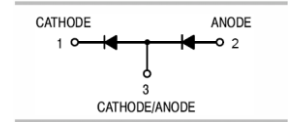
Features

- Fast switching speed
- High conductance
- Halogen free
- Qualified to AEC-Q101 standards for high reliability

HF

Mechanical Data

- Case: SOT-323
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208



SOT-323

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
TBAV99RW	SOT-323	3000 pcs / Tape & Reel	F7

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Repetitive Peak Reverse Voltage	V _{RRM}	70	V
DC Blocking Voltage	V _R	70	V
Forward Continuous Current	I _F	215	mA
Average Rectified Output Current (averaged over any 20ms period) *2	I _{F(AV)}	715	mA
Non-Repetitive Forward Surge Current, 1s	I _{FSM}	0.5	A
Non-Repetitive Forward Surge Current, 1ms	I _{FSM}	1	A
Non-Repetitive Forward Surge Current, 1μs	I _{FSM}	2	A
Peak Forward Surge Current	I _{FM(surge)}	500	mA
Repetitive Peak Forward Surge Current	I _{FRM}	450	mA

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation	P _D	200	mW
Thermal Resistance Junction-to-Air *1	R _{θJA}	466	°C/W
Thermal Resistance Junction-to-Case *1	R _{θJC}	250	°C/W
Thermal Resistance Junction-to-Lead *1	R _{θJL}	271	°C/W
Operating Junction Temperature Range	T _J	-65 ~ +150	°C
Storage Temperature Range	T _{STG}	-65 ~ +150	°C

Notes:

- The data tested by surface mounted on a 15mm * 15mm * 1mm FR4-epoxy P.C.B
- FR-5 = 1.0 * 0.75 * 0.062 in

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage	$V_{(BR)}$	$I_R = 100\mu\text{A}$	70	-	-	V
Forward Voltage	V_F	$I_F = 1\text{mA}$	-	-	0.715	V
		$I_F = 10\text{mA}$	-	-	0.855	V
		$I_F = 50\text{mA}$	-	-	1.000	V
		$I_F = 150\text{mA}$	-	-	1.250	V
Maximum Peak Reverse Current	I_R	$V_R = 70\text{V}$	-	-	2.5	μA
Total Capacitance	C_J	$V_R = 0\text{V}, f = 1.0\text{MHz}$	-	-	1.5	pF
Reverse Recovery Time	t_{rr}	$I_F = I_R = 10\text{mA}$ $I_{rr} = 0.1 \times I_R, R_L = 100\Omega$	-	-	6	ns
Forward Recovery Voltage	V_{FR}	$I_F = 10\text{mA}, t_r = 20\text{ns}$	-	-	1.75	V

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

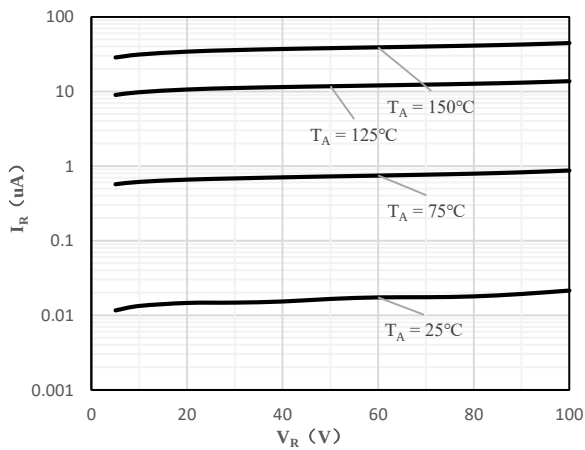


Fig 1 Typical Reverse Characteristic

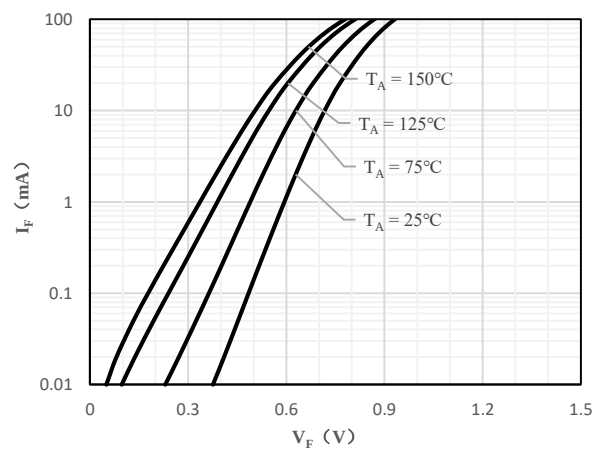


Fig 2 Typical Forward Characteristics

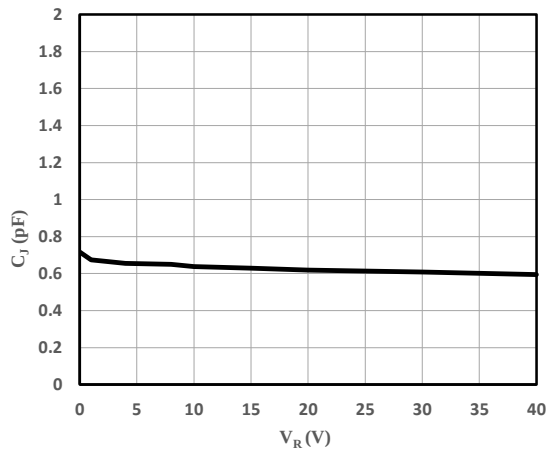


Fig 3 Capacitance vs. Reverse Voltage

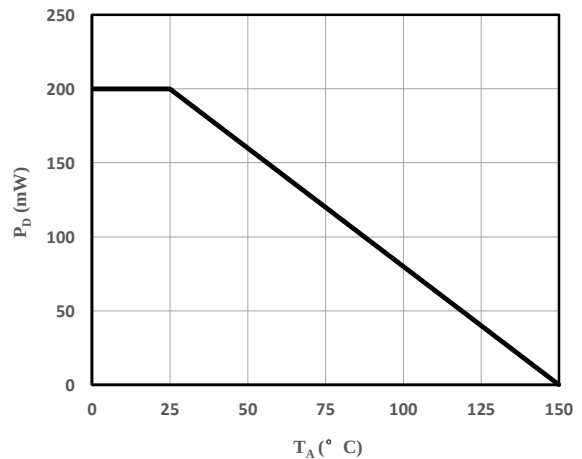
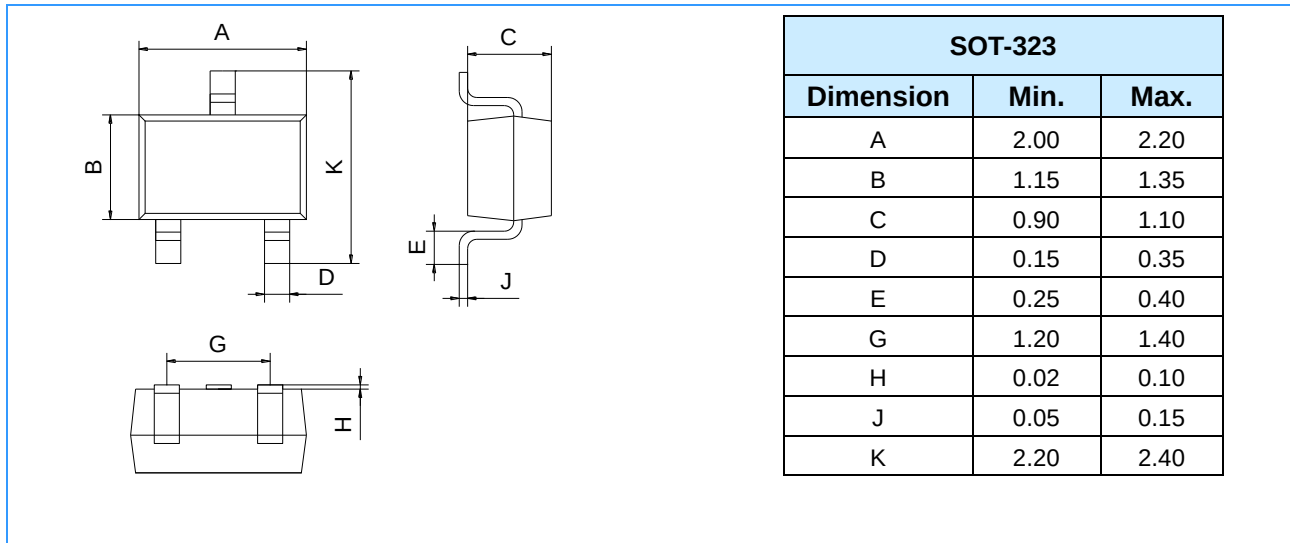
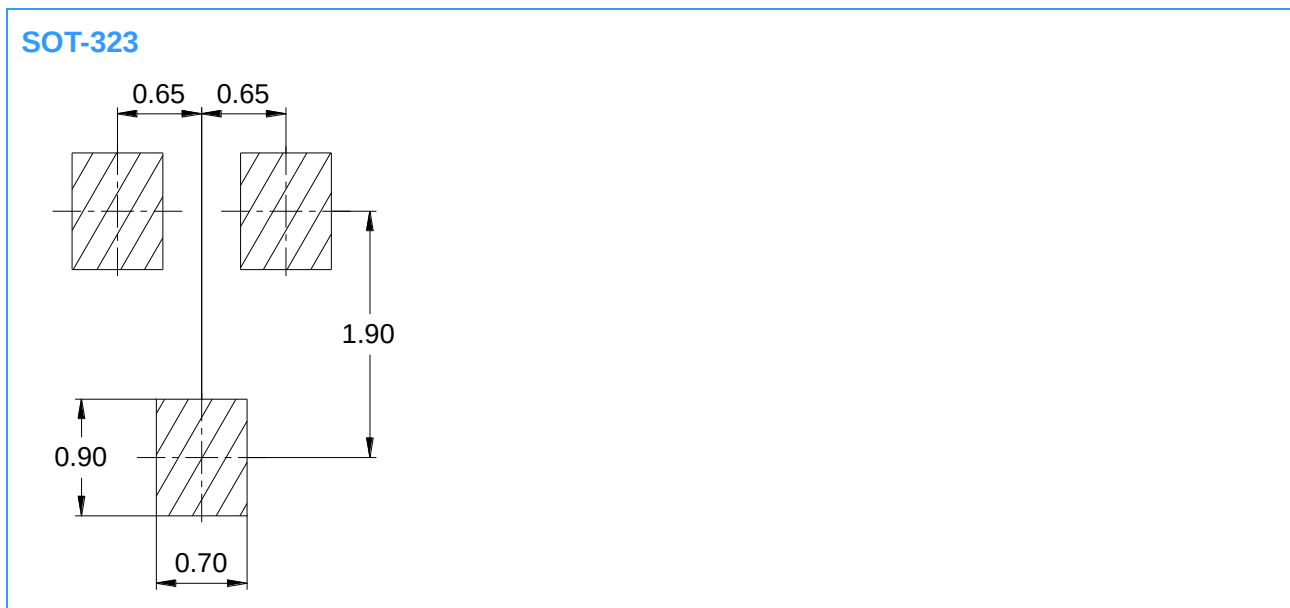


Fig 4 Power Derating Curve

Package Outline Dimensions (Unit: mm)



Mounting Pad Layout (Unit: mm)



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